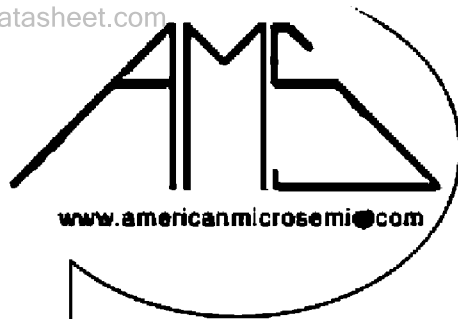




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Discrete Semiconductors

FET's For VHF Amplifiers and Mixers

Type No.	Case	Pol	IGSS max. nA	V _p max. V	Ciss max. pF	Crss max. pF	Y _{fs} min. μmho	G _{ps} min. dB	NF max. dB
2N3823	TO72	N	0.5	8	6	2	3200	200	2.5 100
2N4416	TO72	N	0.1	6	4	0.8	4000	400	4 400
2N4416A	TO72	N	0.1	6	4	0.8	4000	10	400 400
2N5549	TO18	N	0.25	6	8	2	6000		

For Low Noise Amplifiers

Type No.	Case	Pol	BVDG min. V	IGSS max. nA	IDSS min. mA	Y _{fs} min. μmho	V _p max. V	Ciss max. pF	Crss max. pF	en @ 10Hz max. nV/Hz
BFW54	TO72	N	50	0.1	2	3000	6	6	3	100
BFW55	TO72	N	50	0.1	2	3000	6	6	3	40
BFW56	TO72	N	50	0.1	2	3000	6	6	3	20

Dual Gate Mosfets (N Channel Depletion)

Type No.	BV DS V	V _p max. V	Y _{fs} min.-max. mmho	Crss max. pF	GPS min. dB	N.F. max. dB	Notes
3N201	25	5	8-20	0.03	15	200	R.F. Amplifier Mixer I.F. Amplifier I.F. Amplifier } for VHF
3N202	25	5	8-20	0.03	15	200	
3N203	25	5	7-15	0.03	20	45	
3N203A	25	5	7-15	0.03	15	200	
3N204	25	4	10-22	0.03	14	450	R.F. Amplifier Mixer I.F. Amplifier } for VHF
3N205	25	4	10-22	0.03	17	200	
3N206	25	4	7-17	0.03	25	45	
3N211	27	5.5	17-40	0.05	24	200	R.F. Amplifier Mixer I.F. Amplifier } for VHF/UHF
3N212	27	4	17-40	0.05	21	200	
3N213	35	5.5	15-35	0.05	27	45	
3N225	20	4	6-15	0.03	10	900	I.F. Amplifier/ Mixer R.F. Amplifier } for UHF
3N225A	20	3	7.5-15	0.03	14	900	

Case Outline TO72.

Low Leakage/Noise Current

Type No.	Case	Pol.	IGS max. pA	i _n typ. nV.Hz ^{-1/2}	Y _{fs} min. mS	IDSS min. mA	CISS max. pF	en-100kHz max. nV.Hz ^{-1/2}
BF800	TO-72	N	0.5	3 × 10 ⁻¹⁶	0.25	0.3	—	—
BF801	TO-72	N	1.0	4 × 10 ⁻¹⁶	0.25	0.3	—	—
BF802	TO-72	N	5.0	8 × 10 ⁻¹⁶	0.25	0.3	—	—
BF803	TO-72	N	0.5	3 × 10 ⁻¹⁶	0.25	0.3	1.8	12.0
BF804	TO-72	N	0.5	3 × 10 ⁻¹⁶	0.25	0.3	1.8	12.0
BF805	TO-72	N	2.0	6 × 10 ⁻¹⁶	3.0	3.0	3.5	2.4
BF806	TO-72	N	5.0	10 ⁻¹⁵	3.0	3.0	3.5	2.8

Low Leakage

Type No.	Case	Pol	BVGSS min. V	IGSS max. pA	IDSS min. μA	Y _{fs} min. μS	V _p max. V	CISS max. pF
E8517	TO-72	N	40	10	30	70	1.8	2.0
E8517A	TO-72	N	40	1.0	30	70	1.8	2.0
E8518	TO-72	N	40	10	80	80	3.0	2.0
E8518A	TO-72	N	40	1.0	80	80	3.0	2.0
E8519	TO-72	N	40	10	200	100	6.0	2.0
E8519A	TO-72	N	40	1.0	200	100	6.0	2.0